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Details

E·XFI

Product Status	Active
Core Processor	AVR
Core Size	32-Bit Single-Core
Speed	66MHz
Connectivity	CANbus, Ethernet, I ² C, IrDA, LINbus, SPI, UART/USART, USB
Peripherals	Brown-out Detect/Reset, DMA, I ² S, POR, PWM, WDT
Number of I/O	45
Program Memory Size	512KB (512K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	64K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	A/D 11x12b; D/A 2x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 125°C (TA)
Mounting Type	Surface Mount
Package / Case	64-TQFP
Supplier Device Package	64-TQFP (10x10)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/at32uc3c2512c-a2zr

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Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

 Table 3-1.
 GPIO Controller Function Multiplexing

TQFP				G			GPIO function					
/ 	TOEP			P		Pin						
64	100	144	PIN	0	Supply	(1)	Α	в	с	D	Е	F
		14	PB11	43	VDDIO1	x1/x2	USART1 - DSR	SPI0 - MISO	PWM - PWMH[1]			
		15	PB12	44	VDDIO1	x1/x2	USART1 - DCD	SPI0 - SCK	PWM - PWML[2]			
		16	PB13	45	VDDIO1	x1/x2	USART1 - RI	SPI0 - NPCS[0]	PWM - PWMH[2]		MACB - RX_ER	
		17	PB14	46	VDDIO1	x1/x2	USART1 - RTS	SPI0 - NPCS[1]	PWM - PWML[3]		MACB - MDC	
		18	PB15	47	VDDIO1	x1/x2	USART1 - CTS	USART1 - CLK	PWM - PWMH[3]		MACB - MDIO	
		19	PB16	48	VDDIO1	x1/x2	USART1 - RXD	SPI0 - NPCS[2]	PWM - EXT_ FAULTS[0]		CANIF - RXLINE[0]	
		20	PB17	49	VDDIO1	x1/x2	USART1 - TXD	SPI0 - NPCS[3]	PWM - EXT_ FAULTS[1]		CANIF - TXLINE[0]	
		57	PB18	50	VDDIO2	x1/x2	TC0 - CLK2		EIC - EXTINT[4]			
	42	58	PB19	51	VDDIO2	x1/x2	TC0 - A0	SPI1 - MOSI	IISC - ISDO		MACB - CRS	
	43	59	PB20	52	VDDIO2	x1/x2	TC0 - B0	SPI1 - MISO	IISC - ISDI	ACIFA1 - ACAOUT	MACB - COL	
	44	60	PB21	53	VDDIO2	x2/x4	TC0 - CLK1	SPI1 - SCK	IISC - IMCK	ACIFA1 - ACBOUT	MACB - RXD[2]	
	45	61	PB22	54	VDDIO2	x1/x2	TC0 - A1	SPI1 - NPCS[3]	IISC - ISCK	SCIF - GCLK[0]	MACB - RXD[3]	
	46	62	PB23	55	VDDIO2	x1/x2	TC0 - B1	SPI1 - NPCS[2]	IISC - IWS	SCIF - GCLK[1]	MACB - RX_CLK	
		63	PB24	56	VDDIO2	x1/x2	TC0 - CLK0	SPI1 - NPCS[1]				
		64	PB25	57	VDDIO2	x1/x2	TC0 - A2	SPI1 - NPCS[0]	PEVC - PAD_EVT [8]			
		65	PB26	58	VDDIO2	x2/x4	TC0 - B2	SPI1 - SCK	PEVC - PAD_EVT [9]		MACB - TX_EN	
		66	PB27	59	VDDIO2	x1/x2	QDEC0 - QEPA	SPI1 - MISO	PEVC - PAD_EVT [10]	TC1 - CLK0	MACB - TXD[0]	
		67	PB28	60	VDDIO2	x1/x2	QDEC0 - QEPB	SPI1 - MOSI	PEVC - PAD_EVT [11]	TC1 - B0	MACB - TXD[1]	
		68	PB29	61	VDDIO2	x1/x2	QDEC0 - QEPI	SPI0 - NPCS[0]	PEVC - PAD_EVT [12]	TC1 - A0		
31	47	69	PB30	62	VDDIO2	x1						
32	48	70	PB31	63	VDDIO2	x1						
	49	71	PC00	64	VDDIO2	x1/x2	USBC - ID	SPI0 - NPCS[1]	USART2 - CTS	TC1 - B2	CANIF - TXLINE[1]	
	50	72	PC01	65	VDDIO2	x1/x2	USBC - VBOF	SPI0 - NPCS[2]	USART2 - RTS	TC1 - A2	CANIF - RXLINE[1]	



3.2.2 Peripheral Functions

Each GPIO line can be assigned to one of several peripheral functions. The following table describes how the various peripheral functions are selected. The last listed function has priority in case multiple functions are enabled on the same pin.

Table 3-2. Peripheral Functions	able 3-2.	Peripheral Functions
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Function	Description
GPIO Controller Function multiplexing	GPIO and GPIO peripheral selection A to F
Nexus OCD AUX port connections	OCD trace system
aWire DATAOUT	aWire output in two-pin mode
JTAG port connections	JTAG debug port
Oscillators	OSC0, OSC32

3.2.3 Oscillator Pinout

The oscillators are not mapped to the normal GPIO functions and their muxings are controlled by registers in the System Control Interface (SCIF). Please refer to the SCIF chapter for more information about this.

QFN64/ TQFP64 pin	TQFP100 pin	LQFP144 pin	Pad	Oscillator pin
31	47	69	PB30	xin0
	99	143	PB02	xin1
62	96	140	PB00	xin32
32	48	70	PB31	xout0
	100	144	PB03	xout1
63	97	141	PB01	xout32

Table 3-3.Oscillator pinout

3.2.4 JTAG port connections

If the JTAG is enabled, the JTAG will take control over a number of pins, irrespectively of the I/O Controller configuration.

Table 3-4. JTAG pinout

QFN64/ TQFP64 pin	TQFP100 pin	LQFP144 pin	Pin name	JTAG pin
2	2	2	PA01	TDI
3	3	3	PA02	TDO
4	4	4	PA03	TMS
1	1	1	PA00	ТСК

3.2.5 Nexus OCD AUX port connections

If the OCD trace system is enabled, the trace system will take control over a number of pins, irrespectively of the GPIO configuration. Three different OCD trace pin mappings are possible,



Table 3-7.Signal Description List

Signal Name	Function	Туре	Active Level	Comments	
ADCVREFN	Analog negative reference connected to external capacitor	Analog			
	Auxiliary Port -	AUX			
мско	Trace Data Output Clock	Output			
MDO[5:0]	Trace Data Output	Output			
MSEO[1:0]	Trace Frame Control	Output			
EVTI_N	Event In	Output	Low		
EVTO_N	Event Out	Output	Low		
	aWire - AW				
DATA	aWire data	I/O			
DATAOUT	aWire data output for 2-pin mode	I/O			
Controller Area Network Interface - CANIF					
RXLINE[1:0]	CAN channel rxline	I/O			
TXLINE[1:0]	CAN channel txline	I/O			
DAC Interface - DACIFB0/1					
DAC0A, DAC0B	DAC0 output pins of S/H A	Analog			
DAC1A, DAC1B	DAC output pins of S/H B	Analog			
DACREF	Analog reference voltage input	Analog			
External Bus Interface - EBI					
ADDR[23:0]	Address Bus	Output			
CAS	Column Signal	Output	Low		
DATA[15:0]	Data Bus	I/O			
NCS[3:0]	Chip Select	Output	Low		
NRD	Read Signal	Output	Low		
NWAIT	External Wait Signal	Input	Low		
NWE0	Write Enable 0	Output	Low		
NWE1	Write Enable 1	Output	Low		
RAS	Row Signal	Output	Low		
SDA10	SDRAM Address 10 Line	Output			







4.3.1 Pipeline Overview

AVR32UC has three pipeline stages, Instruction Fetch (IF), Instruction Decode (ID), and Instruction Execute (EX). The EX stage is split into three parallel subsections, one arithmetic/logic (ALU) section, one multiply (MUL) section, and one load/store (LS) section.

Instructions are issued and complete in order. Certain operations require several clock cycles to complete, and in this case, the instruction resides in the ID and EX stages for the required number of clock cycles. Since there is only three pipeline stages, no internal data forwarding is required, and no data dependencies can arise in the pipeline.

Figure 4-2 on page 28 shows an overview of the AVR32UC pipeline stages.



6. Supply and Startup Considerations

6.1 Supply Considerations

6.1.1 Power Supplies

The AT32UC3C has several types of power supply pins:

- VDDIO pins (VDDIO1, VDDIO2, VDDIO3): Power I/O lines. Two voltage ranges are available: 5V or 3.3V nominal. The VDDIO pins should be connected together.
- VDDANA: Powers the Analog part of the device (Analog I/Os, ADC, ACs, DACs). 2 voltage ranges available: 5V or 3.3V nominal.
- VDDIN_5: Input voltage for the 1.8V and 3.3V regulators. Two Voltage ranges are available: 5V or 3.3V nominal.
- VDDIN_33:
 - USB I/O power supply
 - if the device is 3.3V powered: Input voltage, voltage is 3.3V nominal.
 - if the device is 5V powered: stabilization for the 3.3V voltage regulator, requires external capacitors
- VDDCORE: Stabilization for the 1.8V voltage regulator, requires external capacitors.
- GNDCORE: Ground pins for the voltage regulators and the core.
- GNDANA: Ground pin for Analog part of the design
- GNDPLL: Ground pin for the PLLs
- GNDIO pins (GNDIO1, GNDIO2, GNDIO3): Ground pins for the I/O lines. The GNDIO pins should be connected together.

See "Electrical Characteristics" on page 49 for power consumption on the various supply pins.

For decoupling recommendations for the different power supplies, please refer to the schematic checklist.

6.1.2 Voltage Regulators

The AT32UC3C embeds two voltage regulators:

- One 1.8V internal regulator that converts from VDDIN_5 to 1.8V. The regulator supplies the output voltage on VDDCORE.
- One 3.3V internal regulator that converts from VDDIN_5 to 3.3V. The regulator supplies the USB pads on VDDIN_33. If the USB is not used or if VDDIN_5 is within the 3V range, the 3.3V regulator can be disabled through the VREG33CTL field of the VREGCTRL SCIF register.

6.1.3 Regulators Connection

The AT32UC3C supports two power supply configurations.

- 5V single supply mode
- 3.3V single supply mode

6.1.3.1 5V Single Supply Mode

In 5V single supply mode, the 1.8V internal regulator is connected to the 5V source (VDDIN_5 pin) and its output feeds VDDCORE.



6.2 Startup Considerations

This chapter summarizes the boot sequence of the AT32UC3C. The behavior after power-up is controlled by the Power Manager. For specific details, refer to the Power Manager chapter.

6.2.1 Starting of clocks

At power-up, the BOD33 and the BOD18 are enabled. The device will be held in a reset state by the power-up circuitry, until the VDDIN_33 (resp. VDDCORE) has reached the reset threshold of the BOD33 (resp BOD18). Refer to the Electrical Characteristics for the BOD thresholds. Once the power has stabilized, the device will use the System RC Oscillator (RCSYS, 115KHz typical frequency) as clock source. The BOD18 and BOD33 are kept enabled or are disabled according to the fuse settings (See the Fuse Setting section in the Flash Controller chapter).

On system start-up, the PLLs are disabled. All clocks to all modules are running. No clocks have a divided frequency, all parts of the system receive a clock with the same frequency as the internal RC Oscillator.

6.2.2 Fetching of initial instructions

After reset has been released, the AVR32UC CPU starts fetching instructions from the reset address, which is 0x8000_0000. This address points to the first address in the internal Flash.

The internal Flash uses VDDIO voltage during read and write operations. It is recommended to use the BOD33 to monitor this voltage and make sure the VDDIO is above the minimum level (3.0V).

The code read from the internal Flash is free to configure the system to use for example the PLLs, to divide the frequency of the clock routed to some of the peripherals, and to gate the clocks to unused peripherals.



Table 7-2. Supply Rise Rates and Order

		Rise Rate				
Symbol	Parameter	Min	Мах	Comment		
V _{VDDIN_5}	DC supply internal 3.3V regulator	0.01 V/ms	1.25 V/us			
V _{VDDIN_33}	DC supply internal 1.8V regulator	0.01 V/ms	1.25 V/us			
V _{VDDIO1} V _{VDDIO2} V _{VDDIO3}	DC supply peripheral I/O	0.01 V/ms	1.25 V/us	Rise after or at the same time as VDDIN_5, VDDIN_33		
V _{VDDANA}	DC supply peripheral I/O and analog part	0.01 V/ms	1.25 V/us	Rise after or at the same time as VDDIN_5, VDDIN_33		

7.3 Maximum Clock Frequencies

These parameters are given in the following conditions:

- V_{VDDCORE} > 1.85V
- Temperature = -40°C to 125°C

Table 7-3.	Clock Frequencies
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Symbol	Parameter	Conditions	Min	Max	Units
f _{CPU}	CPU clock frequency			50	MHz
f _{PBA}	PBA clock frequency			50	MHz
f _{PBB}	PBB clock frequency			50	MHz
f _{PBC}	PBC clock frequency			50	MHz
f _{GCLK0}	GCLK0 clock frequency	Generic clock for USBC		50 ⁽¹⁾	MHz
f _{GCLK1}	GCLK1 clock frequency	Generic clock for CANIF		66 ⁽¹⁾	MHz
f _{GCLK2}	GCLK2 clock frequency	Generic clock for AST		80 ⁽¹⁾	MHz
f _{GCLK4}	GCLK4 clock frequency	Generic clock for PWM		120 ⁽¹⁾	MHz
f _{GCLK11}	GCLK11 clock frequency	Generic clock for IISC		50 ⁽¹⁾	MHz

Note: 1. These values are based on simulation and characterization of other AVR microcontrollers manufactured in the same process technology. These values are not covered by test limits in production.

7.4 Power Consumption

The values in Table 7-4 are measured values of power consumption under the following conditions, except where noted:

- Operating conditions core supply (Figure 7-1)
 - $-V_{VDDIN_5} = V_{VDDIN_{33}} = 3.3V$
 - $V_{VDDCORE} = 1.85V$, supplied by the internal regulator
 - V_{VDDIO1} = V_{VDDIO2} = V_{VDDIO3} = 3.3V
 - $-V_{VDDANA} = 3.3V$



- Internal 3.3V regulator is off
- TA = 25°C
- I/Os are configured as inputs, with internal pull-up enabled.
- Oscillators
 - OSC0/1 (crystal oscillator) stopped
 - OSC32K (32KHz crystal oscillator) stopped
 - PLL0 running
 - PLL1 stopped
- Clocks
 - External clock on XIN0 as main clock source (10MHz)
 - CPU, HSB, and PBB clocks undivided
 - PBA, PBC clock divided by 4
 - All peripheral clocks running

 Table 7-4.
 Power Consumption for Different Operating Modes

Mode	Conditions	Measured on	Consumption Typ	Unit
Active ⁽¹⁾	CPU running a recursive Fibonacci algorithm		512	
Idle ⁽¹⁾			258	
Frozen ⁽¹⁾			106	μΑνινιπΖ
Standby ⁽¹⁾		A	48	
Stop		Amp	73	
DeepStop			43	
Statio	OSC32K and AST running		32	μΑ
Static	AST and OSC32K stopped		31	

Note: 1. These numbers are valid for the measured condition only and must not be extrapolated to other frequencies.



Figure 7-1. Measurement Schematic



7.4.1 Peripheral Power Consumption

The values in Table 7-5 are measured values of power consumption under the following conditions.

• Operating conditions core supply (Figure 7-1)

 $-V_{VDDIN_5} = V_{DDIN_{33}} = 3.3V$

- $V_{VDDCORE} = 1.85V$, supplied by the internal regulator
- V_{VDDIO1} = V_{VDDIO2} = V_{VDDIO3} = 3.3V
- $V_{VDDANA} = 3.3V$
- Internal 3.3V regulator is off.
- TA = 25°C
- I/Os are configured as inputs, with internal pull-up enabled.
- Oscillators
 - OSC0/1 (crystal oscillator) stopped
 - OSC32K (32KHz crystal oscillator) stopped
 - PLL0 running



7.7 Flash Characteristics

Table 7-15 gives the device maximum operating frequency depending on the number of flash wait states. The FSW bit in the FLASHC FSR register controls the number of wait states used when accessing the flash memory.

 Table 7-15.
 Maximum Operating Frequency

Flash Wait States	Read Mode	Maximum Operating Frequency
0	1 cycle	25MHz
1	2 cycles	50MHz

Table 7-16. Flash Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t _{FPP}	Page programming time			17		
t _{FPE}	Page erase time	f 50MU-		17		
t _{FFP}	Fuse programming time	$I_{CLK_{HSB}} = 50101HZ$		1.3		ms
t _{FEA}	Full chip erase time (EA)			18.3		
t _{FCE}	JTAG chip erase time (CHIP_ERASE)	f _{CLK_HSB} = 115kHz		640		

Table 7-17. Flash Endurance and Data Retention

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
N _{FARRAY}	Array endurance (write/page)		10k			cycles
N _{FFUSE}	General Purpose fuses endurance (write/bit)		500			cycles
t _{RET}	Data retention		15			years



 Table 7-29.
 ADC Decoupling requirements

Symbol	Parameter	Conditions	Min	Тур	Мах	Units
CADCREFPN	ADCREFP/ADCREFN capacitance	No voltage reference appplied on ADCREFP/ADCREFN		100		nF

Table 7-30. ADC Inputs

Symbol	Parameter	Conditions	Min	Тур	Max	Units
V _{ADCINn}	ADC input voltage range		0		V _{VDDANA}	V
<u> </u>	Internal Capacitance	ADC used without S/H			5	۳E
CONCHIP		ADC used with S/H			4	рг
R _{ONCHIP}	Switch resistance	ADC used without S/H			5.1	kΩ
		ADC used with S/H			4.6	





Symbol	Parameter	Conditions	Min	Тур	Max	Units
RES	Resolution	Differential mode,			12	Bit
INL	Integral Non-Linearity	$V_{VDDANA} = 3V,$			6	LSB
DNL	Differential Non-Linearity	$V_{ADCREF0} = 1V,$			5	LSB
	Offset error	ADCFIA.SEQCFGn.SRES = 0	-10		10	mV
	Gain error	$(F_{adc} = 1.2MHz)$	-30		30	mV



Symbol	Parameter	Conditions	Min	Тур	Max	Units
RES	Resolution	Differential mode,			12	Bit
INL	Integral Non-Linearity	V _{VDDANA} = 3V,			6	LSB
DNL	Differential Non-Linearity	$V_{ADCREF0} = 1V,$ ADCFIA.SEQCFGn.SRES = 0, S/H gain = 1			5	LSB
	Offset error		-10		10	mV
	Gain error $Grade = 1.2$ Gain error($F_{adc} = 1.2$	$(F_{adc} = 1.2MHz)$	-30		30	mV
RES	Resolution	Differential mode,			12	Bit
INL	Integral Non-Linearity	$V_{VDDANA} = 5V,$			6	LSB
DNL	Differential Non-Linearity	$V_{ADCREF0} = 3V,$			4	LSB
	Offset error	= ADCFIA.SEQCFGn.SRES = 0,	-15		15	mV
	Gain error $(F_{adc} = 1.5MHz)$	-30		30	mV	

Table 7-34. ADC and S/H Transfer Characteristics 12-bit Resolution Mode and S/H gain = $1^{(1)}$

Note: 1. The measures are done without any I/O activity on VDDANA/GNDANA power domain.

Table 7-35.	ADC and S/H Transfer Characteristics 12-b	it Resolution Mode and S/H gain from 1 to 8 ⁽¹⁾
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Symbol	Parameter	Conditions	Min	Тур	Max	Units
RES	Resolution	Differential mode,			12	Bit
INL	Integral Non-Linearity	$V_{VDDANA} = 3V,$			30	LSB
DNL	Differential Non-Linearity	$V_{ADCREF0} = 1V,$ $ADCFIA.SEQCFGn.SRES = 0,$ $S/H \text{ gain from 1 to 8}$ $(F_{adc} = 1.2MHz)$			30	LSB
	Offset error		-10		10	mV
	Gain error		-25		25	mV
RES	Resolution	Differential mode,			12	Bit
INL	Integral Non-Linearity	$V_{VDDANA} = 5V,$			10	LSB
DNL	Differential Non-Linearity	$V_{ADCREF0} = 3V,$			15	LSB
	Offset error	= ADCFIA.SEQCFGn.SRES = 0,	-20		20	mV
	Gain error	$(F_{adc} = 1.5 MHz)$	-30		30	mV

Note: 1. The measures are done without any I/O activity on VDDANA/GNDANA power domain

Table 7-36.	ADC and S/H Transfer	Characteristics	10-bit Resolution	Mode and S/H gain from 1	to 16 ⁽¹⁾
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Symbol	Parameter	Conditions	Min	Тур	Max	Units
RES	Resolution	Differential mode,			10	Bit
INL	Integral Non-Linearity	$V_{VDDANA} = 3V,$			4	LSB
DNL	Differential Non-Linearity	$V_{ADCREF0} = 1V,$			4	LSB
	Offset error	ADCFIA.SEQUEGN.SRES = 1, S/H gain from 1 to 16	-15		15	mV
	Gain error	$(F_{adc} = 1.5 MHz)$	-25		25	mV



Symbol	Parameter	Conditions	Min	Max	Units
SPI6	SPCK falling to MISO delay			31	ns
SPI7	MOSI setup time before SPCK rises		0		ns
SPI8	MOSI hold time after SPCK rises		7		ns
SPI9	SPCK rising to MISO delay			32	ns
SPI10	MOSI setup time before SPCK falls	external	1.5		ns
SPI11	MOSI hold time after SPCK falls	capacitor =	5		ns
SPI12	NPCS setup time before SPCK rises		4		ns
SPI13	NPCS hold time after SPCK falls		2.5		ns
SPI14	NPCS setup time before SPCK falls		3.5		ns
SPI15	NPCS hold time after SPCK rises		2.5		ns

Table 7-49.SPI Timing, Slave Mode⁽¹⁾

Note: 1. These values are based on simulation and characterization of other AVR microcontrollers manufactured in the same process technology. These values are not covered by test limits in production.

Maximum SPI Frequency, Slave Input Mode

The maximum SPI slave input frequency is given by the following formula:

$$f_{SPCKMAX} = MIN(f_{CLKSPI}, \frac{1}{SPIn})$$

Where *SPIn* is the MOSI setup and hold time, SPI7 + SPI8 or SPI10 + SPI11 depending on CPOL and NCPHA. f_{CLKSPI} is the maximum frequency of the CLK_SPI. Refer to the SPI chapter for a description of this clock.

Maximum SPI Frequency, Slave Output Mode

The maximum SPI slave output frequency is given by the following formula:

$$f_{SPCKMAX} = MIN(f_{PINMAX}, \frac{1}{SPIn + t_{SETUP}})$$

Where *SPIn* is the MISO delay, SPI6 or SPI9 depending on CPOL and NCPHA. t_{SETUP} is the SPI master setup time. Please refer to the SPI masterdatasheet for t_{SETUP} . f_{PINMAX} is the maximum frequency of the SPI pins. Please refer to the I/O Pin Characteristics section for the maximum frequency of the pins.

7.9.5 TWIM/TWIS Timing

Figure 7-50 shows the TWI-bus timing requirements and the compliance of the device with them. Some of these requirements (t_r and t_f) are met by the device without requiring user intervention. Compliance with the other requirements (t_{HD-STA} , t_{SU-STA} , t_{SU-STO} , t_{HD-DAT} , $t_{SU-DAT-I2C}$, $t_{LOW-I2C}$, t_{HIGH} , and f_{TWCK}) requires user intervention through appropriate programming of the relevant



7.9.6 JTAG Timing



Figure 7-16. JTAG Interface Signals

Table 7-51.	JTAG Timings ⁽¹⁾
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Symbol	Parameter	Conditions	Min	Max	Units
JTAG0	TCK Low Half-period	external capacitor =	23		ns
JTAG1	TCK High Half-period		9		ns
JTAG2	TCK Period		31		ns
JTAG3	TDI, TMS Setup before TCK High		7		ns
JTAG4	TDI, TMS Hold after TCK High		0		ns
JTAG5	TDO Hold Time		13.5		ns
JTAG6	TCK Low to TDO Valid	40pF		23	ns
JTAG7	Boundary Scan Inputs Setup Time		0		ns
JTAG8	Boundary Scan Inputs Hold Time		4.5		ns
JTAG9	Boundary Scan Outputs Hold Time		12		ns
JTAG10	TCK to Boundary Scan Outputs Valid			19	ns

Note: 1. These values are based on simulation and characterization of other AVR microcontrollers manufactured in the same process technology. These values are not covered by test limits in production.



7.9.7 EBI Timings

See EBI I/O lines description for more details.

Table 7-52.SMC Clock Signal.

Symbol	Parameter	Max ⁽¹⁾	Units
1/(t _{CPSMC})	SMC Controller clock frequency	f _{cpu}	MHz

Note: 1. The maximum frequency of the SMC interface is the same as the max frequency for the HSB.

Table 7-53. SMC Read Signals with Hold Settings⁽¹⁾

Symbol	Parameter	Conditions	Min	Units					
NRD Controlled (READ_MODE = 1)									
SMC ₁	Data setup before NRD high		34.4						
SMC ₂	Data hold after NRD high		0						
SMC ₃	NRD high to NBS0/A0 change ⁽²⁾	V _{VDD} = 3.0V,	nrd hold length * tcpsmc - 1.5						
SMC ₄	NRD high to NBS1 change ⁽²⁾	drive strength of the	nrd hold length * tсрѕмс - 0	ns					
SMC ₅	NRD high to NBS2/A1 change ⁽²⁾	external capacitor =	nrd hold length * tсрѕмс - 0						
SMC ₇	NRD high to A2 - A25 change ⁽²⁾	40pF	nrd hold length * tcpsmc - 5.9						
SMC ₈	NRD high to NCS inactive ⁽²⁾		(nrd hold length - ncs rd hold length) * tcPSMc - 1.3						
SMC ₉	NRD pulse width		nrd pulse length * tcpsмc - 0.9						
NRD Controlled (READ_MODE = 0)									
SMC ₁₀	Data setup before NCS high		36.1	ns					
SMC ₁₁	Data hold after NCS high		0						
SMC ₁₂	NCS high to NBS0/A0 change ⁽²⁾	V - 3.0V	ncs rd hold length * tcpsмc - 3.2						
SMC ₁₃	NCS high to NBS0/A0 change ⁽²⁾	$v_{VDD} = 3.0 v_{,}$ drive strength of the	ncs rd hold length * tcpsмc - 2.2						
SMC ₁₄	NCS high to NBS2/A1 change ⁽²⁾	pads set to the lowest,	ncs rd hold length * tcpsмc - 1.2						
SMC ₁₆	NCS high to A2 - A25 change ⁽²⁾	external capacitor = 40pF	ncs rd hold length * tcpsmc - 7.6						
SMC ₁₇	NCS high to NRD inactive ⁽²⁾		(ncs rd hold length - nrd hold length) * tcPSMc - 2.4						
SMC ₁₈	NCS pulse width		ncs rd pulse length * tcpsмc - 3.3	1					

Note: 1. These values are based on simulation and characterization of other AVR microcontrollers manufactured in the same process technology. These values are not covered by test limits in production.

2. hold length = total cycle duration - setup duration - pulse duration. "hold length" is for "ncs rd hold length" or "nrd hold length".



10.1.5 SCIF

1 PLLCOUNT value larger than zero can cause PLLEN glitch

Initializing the PLLCOUNT with a value greater than zero creates a glitch on the PLLEN signal during asynchronous wake up.

Fix/Workaround

The lock-masking mechanism for the PLL should not be used.

The PLLCOUNT field of the PLL Control Register should always be written to zero.

2 PLL lock might not clear after disable

Under certain circumstances, the lock signal from the Phase Locked Loop (PLL) oscillator may not go back to zero after the PLL oscillator has been disabled. This can cause the propagation of clock signals with the wrong frequency to parts of the system that use the PLL clock.

Fix/Workaround

PLL must be turned off before entering STOP, DEEPSTOP or STATIC sleep modes. If PLL has been turned off, a delay of 30us must be observed after the PLL has been enabled again before the SCIF.PLL0LOCK bit can be used as a valid indication that the PLL is locked.

3 BOD33 reset locks the device

If BOD33 is enabled as a reset source (SCIF.BOD33.CTRL=0x1) and when VDDIN_33 power supply voltage falls below the BOD33 voltage (SCIF.BOD33.LEVEL), the device is locked permanently under reset even if the power supply goes back above BOD33 reset level. In order to unlock the device, an external reset event should be applied on RESET_N. **Fix/Workaround**

Use an external BOD on VDDIN_33 or an external reset source.

10.1.6 SPI

1 SPI data transfer hangs with CSR0.CSAAT==1 and MR.MODFDIS==0

When CSR0.CSAAT==1 and mode fault detection is enabled (MR.MODFDIS==0), the SPI module will not start a data transfer. **Fix/Workaround**

Fix/Workaround

Disable mode fault detection by writing a one to MR.MODFDIS.

2 Disabling SPI has no effect on the SR.TDRE bit

Disabling SPI has no effect on the SR.TDRE bit whereas the write data command is filtered when SPI is disabled. Writing to TDR when SPI is disabled will not clear SR.TDRE. If SPI is disabled during a PDCA transfer, the PDCA will continue to write data to TDR until its buffer is empty, and this data will be lost.

Fix/Workaround

Disable the PDCA, add two NOPs, and disable the SPI. To continue the transfer, enable the SPI and PDCA.

3 SPI disable does not work in SLAVE mode

SPI disable does not work in SLAVE mode.

Fix/Workaround

Read the last received data, then perform a software reset by writing a one to the Software Reset bit in the Control Register (CR.SWRST).



10.2.12 WDT

1 Clearing the Watchdog Timer (WDT) counter in second half of timeout period will issue a Watchdog reset

If the WDT counter is cleared in the second half of the timeout period, the WDT will immediately issue a Watchdog reset.

Fix/Workaround

Use twice as long timeout period as needed and clear the WDT counter within the first half of the timeout period. If the WDT counter is cleared after the first half of the timeout period, you will get a Watchdog reset immediately. If the WDT counter is not cleared at all, the time before the reset will be twice as long as needed.

2 WDT Control Register does not have synchronization feedback

When writing to the Timeout Prescale Select (PSEL), Time Ban Prescale Select (TBAN), Enable (EN), or WDT Mode (MODE) fieldss of the WDT Control Register (CTRL), a synchronizer is started to propagate the values to the WDT clcok domain. This synchronization takes a finite amount of time, but only the status of the synchronization of the EN bit is reflected back to the user. Writing to the synchronized fields during synchronization can lead to undefined behavior.

Fix/Workaround

-When writing to the affected fields, the user must ensure a wait corresponding to 2 clock cycles of both the WDT peripheral bus clock and the selected WDT clock source.

-When doing writes that changes the EN bit, the EN bit can be read back until it reflects the written value.



11. Datasheet Revision History

Please note that the referring page numbers in this section are referred to this document. The referring revision in this section are referring to the document revision.

11.1 Rev. D - 01/12

- 1 Errata: Updated
- 2 PM: Clock Mask Table Updated
- 3 Fixed PLLOPT field description in SCIF chapter
- 4 MDMA: Swapped bit descriptions for IER and IDR
- 5 MACB: USRIO register description and bit descriptions for IMR/IDR/IER Updated
- 6 USBC: UPCON.PFREEZE and UPINRQn description Updated
- 7 ACIFA: Updated
- 8 ADCIFA: CFG.MUXSET, SSMQ description and conversion results section Updated
- 9 DACIFB: Calibration section Updated
- 10 Electrical Characteristics: ADCREFP/ADCREFN added
- 11 Add devices: C1256C, C2256C, C2128C

11.2 Rev. C - 08/11

Electrical Characteristics Updated:

- I/O Pins characteristics
- 8MHz/1MHz RC Oscillator (RC8M) characteristics
- 1.8V Voltage Regulator characteristics
- 3.3V Voltage Regulator characteristics
- 1.8VBrown Out Detector (BOD18) characteristics
- 3.3VBrown Out Detector (BOD33) characteristics
- 5VBrown Out Detector (BOD50) characteristics
- Analog to Digital Converter (ADC) and sample and hold (S/DH) Characteristics
- Analog Comparator characteristics
- 2 Errata: Updated

1

3 TWIS: Updated

11.3 Rev. B – 02/11

- 1 Package and pinout: Added supply column. Updated peripheral functions
- 2 Supply and Startup Considerations: Updated I/O lines power
- 3 PM: Added AWEN description



AT32UC3C

- 4 SCIF: Added VREGCR register
- 5 AST: Updated digital tuner formula
- 6 SDRAMC: cleaned-up SDCS/NCS names. Added VERSION register
- 7 SAU: Updated SR.IDLE
- 8 USART: Updated
- 9 CANIF: Updated address map figure
- 10 USBC: Updated
- 11 DACIFB: Updated
- 12 Programming and Debugging: Added JTAG Data Registers section
- 13 Electrical Characteristics: Updated
- 14 Ordering Information: Updated
- 15 Errata: Updated

11.4 Rev. A - 10/10

1 Initial revision





Headquarters

Atmel Corporation 2325 Orchard Parkway San Jose, CA 95131 USA Tel: 1(408) 441-0311 Fax: 1(408) 487-2600

International

Atmel Asia Unit 1-5 & 16, 19/F BEA Tower, Millennium City 5 418 Kwun Tong Road Kwun Tong, Kowloon Hong Kong Tel: (852) 2245-6100 Fax: (852) 2722-1369 Atmel Europe Le Krebs 8, Rue Jean-Pierre Timbaud BP 309 78054 Saint-Quentin-en-Yvelines Cedex France Tel: (33) 1-30-60-70-00 Fax: (33) 1-30-60-71-11

Atmel Japan

9F, Tonetsu Shinkawa Bldg. 1-24-8 Shinkawa Chuo-ku, Tokyo 104-0033 Japan Tel: (81) 3-3523-3551 Fax: (81) 3-3523-7581

Product Contact

Web Site www.atmel.com Technical Support avr32@atmel.com Sales Contact www.atmel.com/contacts

Literature Requests www.atmel.com/literature

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